

NON-ISOLATED BUCK LED LIGHTING DRIVE IC WITH LOW POWER AND HIGH CONSTANT CURRENT ACCURACY

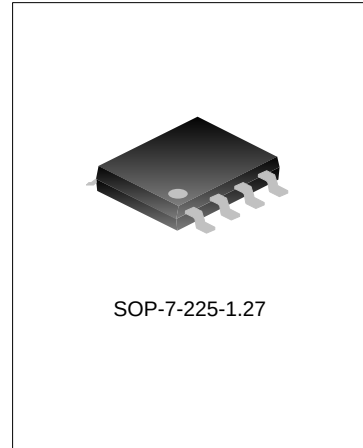
DESCRIPTION

SD670XS is designed for non-isolated LED driving with floating Buck structure, and high constant current accuracy and high linear/load regulation available with assistant of special sense technology.

SD670XS integrates various protections, such as output open/short circuit protection, cycle-by-cycle current limit protection and over temperature protection.

The start-up current and operating current are low and highlight LED can be driven with high efficiency in full range (85VAC~265VAC).

SD670XS integrates high voltage power MOSFET, reducing the system cost and the whole volume.



FEATURES

- ◆ Built-in 500V high voltage power MOSFET
- ◆ Constant current with high accuracy for LED ($<\pm 3\%$)
- ◆ Output open/short circuit protection
- ◆ CS open/short circuit protection
- ◆ VCC undervoltage protection
- ◆ Over temperature protection
- ◆ Cycle-by-cycle current protection
- ◆ No auxiliary winding

APPLICATION

- ◆ Bulb Lamp
- ◆ T5/T8 LED Lamp
- ◆ Various LED Lighting

ORDERING INFORMATION

Part No.	Package	Hazardous Substance Control	Packing
SD6701ASTR	SOP-7-225-1.27	Halogen free	Tape&Reel
SD6701STR	SOP-7-225-1.27	Halogen free	Tape&Reel
SD6702STR	SOP-7-225-1.27	Halogen free	Tape&Reel
SD6703STR	SOP-7-225-1.27	Halogen free	Tape&Reel
SD6704STR	SOP-7-225-1.27	Halogen free	Tape&Reel

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Characteristics		Symbol	Rating	Unit
Drain-Gate voltage (R _{GS} =1MW)		V _{DGR}	500	V
Gate-Source Voltage		V _{GS}	±30	V
Drain current pulse	SD6701AS	I _{DM}	2.4	A
	SD6701S		4	
	SD6702S		8	
	SD6703S		10	
	SD6704S		12	
Drain continuous current (Tamb=25°C)	SD6701AS	I _D	0.8	A
	SD6701S		1	
	SD6702S		2	
	SD6703S		3	
	SD6704S		4	
Supply voltage		V _{CC}	-0.3~17	V
ROVP voltage		V _{ROVP}	-0.3~6.5	V
Sense voltage		V _{CS}	-0.3~6.5	V
DRAIN voltage		V _{DRAIN}	-0.3~500	V
Junction temperature Range		T _j	-40~150	°C
Storage temperature Range		T _s	-55~150	°C

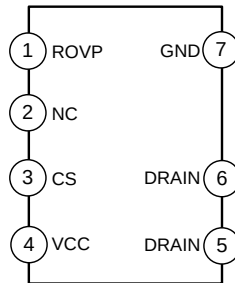
ELECTRICAL CHARACTERISTICS (Unless otherwise stated, $V_{CC}=12V$, $T_{amb}=25^{\circ}C$)

Characteristics		Symbol	Test condition	Min.	Typ.	Max.	Unit
VCC clamp voltage		VCC_CLAMP	I_VCC=0.5mA	14	16	17.6	V
UVLO VH		UVLO_H		11.3	12.7	14.1	V
UVLO VL		UVLO_L		7	8	9	V
Start-up current		I_START	V_CC=10V	50	95	125	μA
Operating current		I_VCC	CS=1V	100	175	250	μA
Protection current		I_PRO	CS=5V	800	1200	2000	μA
CC parameters							
CS reference voltage ^{Note1}		CS_REF		388	400	412	mV
CS current limit reference voltage		CS_PEAK		400	525	650	mV
Time Parameters							
Max. on time		T_ON,MAX		30	38	47	μs
LEB		T_LEB		0.45	0.7	0.95	μs
Max. off time		T_OFF,MAX		40	52	64	μs
Min. off time		T_OFF,MIN		2.5	3.5	4.5	μs
Min. period		T_MIN		3.7	5	6.3	μs
ROVP voltage		V_ROVP		2	2.4	2.8	V
Internal high voltage MOSFET							
On resistance	SD6701AS	R_DS(on)	V_GS=12V, I_D=0.1A	--	13	14.5	Ω
	SD6701S			--	7.5	8.6	
	SD6702S			--	5	5.7	
	SD6703S			--	2.8	3.3	
	SD6704S			--	1.9	2.5	
withstand voltage at Drain	SD6701AS	BV_DSS	V_GS=0V, I_D=50uA	500	550	--	V
	SD6701S			500	550	--	
	SD6702S			500	550	--	
	SD6703S			500	550	--	
	SD6704S			500	550	--	
Zero gate voltage drain current	SD6701AS	I_DSS	V_DS=500V, V_GS=0V	--	--	1.0	μA
	SD6701S			--	--	1.0	
	SD6702S			--	--	1.0	
	SD6703S			--	--	1.0	
	SD6704S			--	--	1.0	
Gate-Source Leakage Current	SD6701AS	I_GSS	V_GS=±30V, V_DS=0V	--	--	±100	nA
	SD6701S			--	--	±100	
	SD6702S			--	--	±100	
	SD6703S			--	--	±100	
	SD6704S			--	--	±100	

Characteristics	Symbol	Test condition	Min.	Typ.	Max.	Unit
Temperature characteristics						
Regulatory temperature threshold value	T_{REG}		125	140	155	°C
Over temperature protection threshold value	T_{SD}		135	150	165	°C
Over temperature protection release point	$T_{RECOVERY}$		115	130	145	°C

Note 1: in the test, CS reference voltage will be multiplied by 1.1, that is 440mV displayed as the center value and the range is 430mV~450mV.

PIN CONFIGURATIONS



PIN DESCRIPTION

Pin No.	Pin Name	I/O	Description
1	ROVP	I/O	OVP pin, connected to GND through a resistor
2	NC	-	-
3	CS	I	Sense current pin
4	VCC	POWER	Power supply
5, 6	DRAIN	O	Drain of internal high voltage MOSFET
7	GND	GND	GND

FUNCTION DESCRIPTION

SD670XS is a non-isolated LED driver IC adopting BUCK structure with internal high voltage power MOSFET. The function is described below.

Start control

For SD670XS, no auxiliary winding is needed. The bus voltage charges capacitor of VCC through start resistor. The operating current should be as low as possible for high conversion efficiency. It features undervoltage protection at VCC and the on/off threshold value are 13V and 8V. The hysteresis characteristic guarantees that the IC can be powered by the capacitor during the start.

Constant current accuracy control

IC senses the MOSFET current, which is input to Gm amplifier together with internal reference voltage for error amplification, to obtain high constant current accuracy and high linear/load regulation rate.

CS voltage and 400mV reference voltage are the inputs of Gm amplifier, and then the output is integrated through internal COMP capacitor.

$$I_{OUT}=400mV/2 \cdot R_{CS}.$$

Boundary-conduction mode

SD670XS works in boundary-conduction mode with strong anti-interference and high conversion efficiency. Auxiliary winding is unnecessary to detect zero-crossing current and the peripheral circuit is simple.

Current detection and LEB

With the cycle-by-cycle current limit function, internal switch M1 will be turned off if CS voltage exceeds 525mV. System still works and internal switch M1 is turned on in the next period. There is no LEB for current limit comparator. CS voltage and COMP voltage are compared by COMP comparator, if CS voltage is higher than COMP, internal switch M1 is off and system keeps work. During the instant of turning on internal switch M1, 0.7us LEB is used for avoiding the error operation on internal switch M1.

CS open/short circuit protection(also called as max. output current limit)

If CS resistor is shorted, there is no limit for inductor current, voltage on pin CS is zero, and the short-circuit is judged by checking voltage during on of internal OUT signal. OUT limit voltage are different for different products of SD670XS series. Please refer to Application Note for detailed max. output current limit.

Source driver

Source drive is adopted for this IC. Gate of M2 is connected to VCC through a resistor, Source is connected to Drain of internal switch M1. When Gate of internal switch M1 is driven by IC, the IC current can be reduced because of the low gate capacitance of M1.

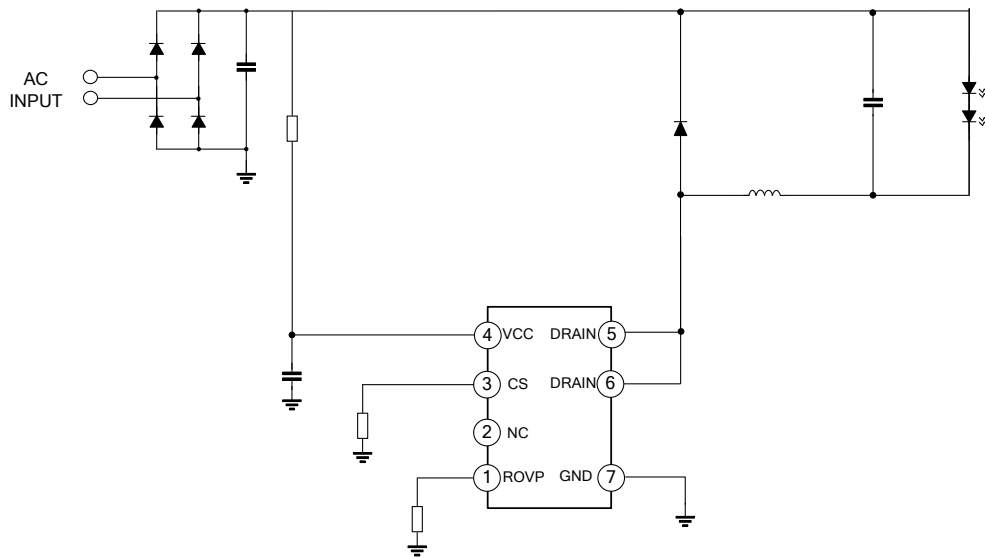
Output open circuit protection

There is no signal which reflects the output, the IC detects the discharge time for judging over voltage. The over voltage protection threshold value is set through pin ROVP. ROVP pin should be grounded via a pull-down resistor, floated is not allowed. Please refer to application note for resistance range and detailed operations.

Internal temperature regulatory

The output current will be reduced if the IC temperature exceeds the certain value.

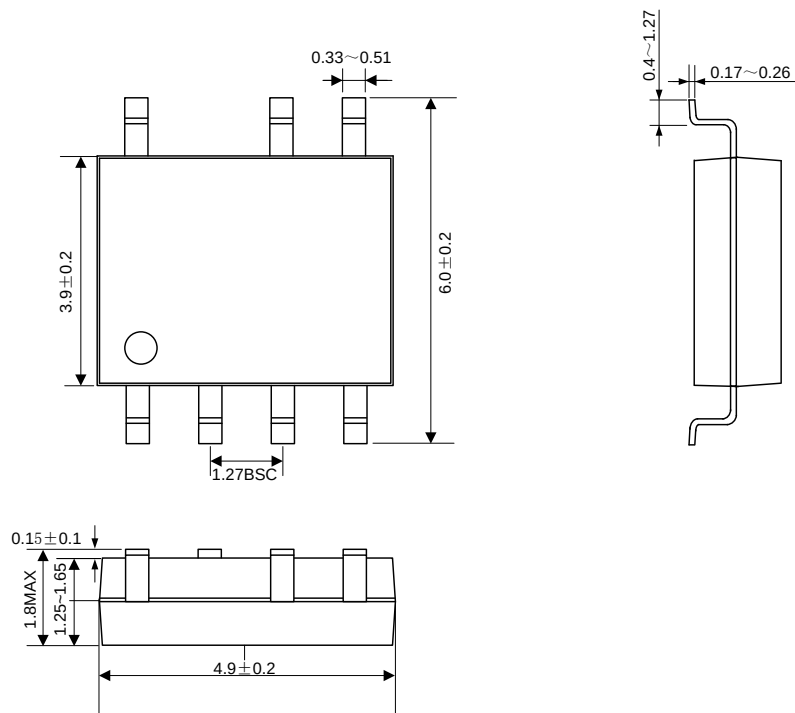
TYPICAL APPLICATION CIRCUIT



PACKAGE OUTLINE

SOP-7-225-1.27

UNIT: mm



**MOS DEVICES OPERATE NOTES:**

Electrostatic charges may exist in many things. Please take following preventive measures to prevent effectively the MOS electric circuit as a result of the damage which is caused by discharge:

- The operator must put on wrist strap which should be earthed to against electrostatic.
- Equipment cases should be earthed.
- All tools used during assembly, including soldering tools and solder baths, must be earthed.
- MOS devices should be packed in antistatic/conductive containers for transportation.

Disclaimer :

- Silan reserves the right to make changes to the information herein for the improvement of the design and performance without prior notice! Customers should obtain the latest relevant information before placing orders and should verify that such information is complete and current.
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2. Modify the function description			
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Revision History:			
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Rev.:	1.6	Author:	Yao Feng
Revision History:			
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2. Modify the function description			
Rev.:	1.5	Author:	Yao Feng
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